



N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
30	0.0045 at V _{GS} = 10 V	20		
	0.0055 at V _{GS} = 4.5 V	19		

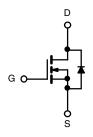
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFET
- Optimized for "Low Side" Synchronous **Rectifier Operation**
- 100 % R_g Tested

HALOGEN FREE Available

APPLICATIONS

- DC/DC Converters
- Synchronous Rectifiers



N-Channel MOSFET

		SO-8		
S			8	D
S	2		7	D
S	3		6	D
G	4		5	D
		- \ \ (
		Top View		

Ordering Information: Si4364DY-T1-E3 (Lead (Pb)-free) Si4364DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	Γ _A = 25 °C, unle	ss otherwise r	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 16		
Continuous Drain Current (T _{.I} = 150 °C) ^a	T _A = 25 °C	- I _D	20	13	
Continuous Diain Current (1) = 130 C)	T _A = 70 °C		15	10	Α
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	60		^
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3	
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D	3.5	1.6	W
iviaximum rowei Dissipation	T _A = 70 °C		2.2	1	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 s	R _{thJA}	29	35		
Maximum Junction-to-Ambient ^a	Steady State		67	80	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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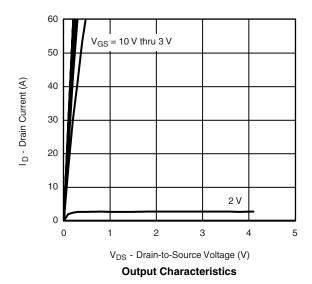
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	<u> </u>		<u>'</u>			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.8		1.8	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 16 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V			1	
		V_{DS} = 30 V, V_{GS} = 0 V, T_{J} = 55 °C			5	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α
Drain-Source On-State Resistance ^a	В	V _{GS} = 10 V, I _D = 20 A		0.0035	0.0045	-
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 19 \text{ A}$		0.0043	0.0055	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		90		S
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.70	1.1	V
Dynamic ^b	•		•			
Total Gate Charge	Q_g			48	75	
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		16		nC
Gate-Drain Charge	Q _{gd}			11		
Gate Resistance R _g			0.5	1.1	1.9	Ω
Turn-On Delay Time	t _{d(on)}			17	30	
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		16	30	
Turn-Off Delay Time	$t_{d(off)}$ $I_D \cong 1 \text{ A, V}_{GEN} = 4.5 \text{ V, R}_g =$	$I_D\cong$ 1 A, V_{GEN} = 4.5 V, R_g = 6 Ω	165	250	ns	
Fall Time	t _f			55	90	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		40	80	

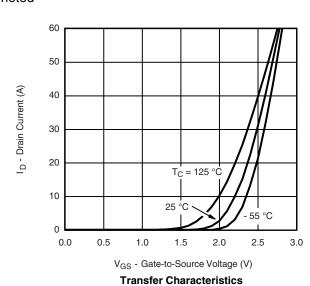
Notes:

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



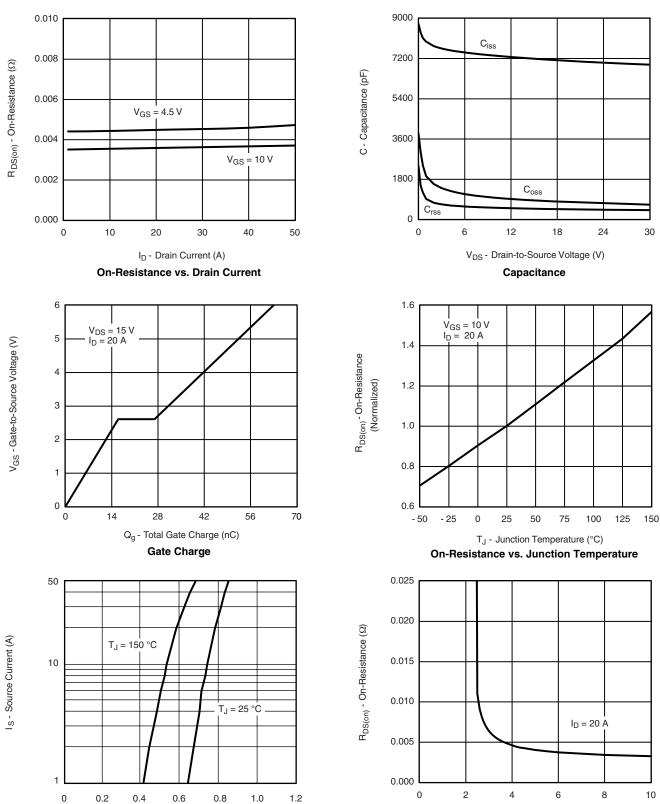








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V_{SD} - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

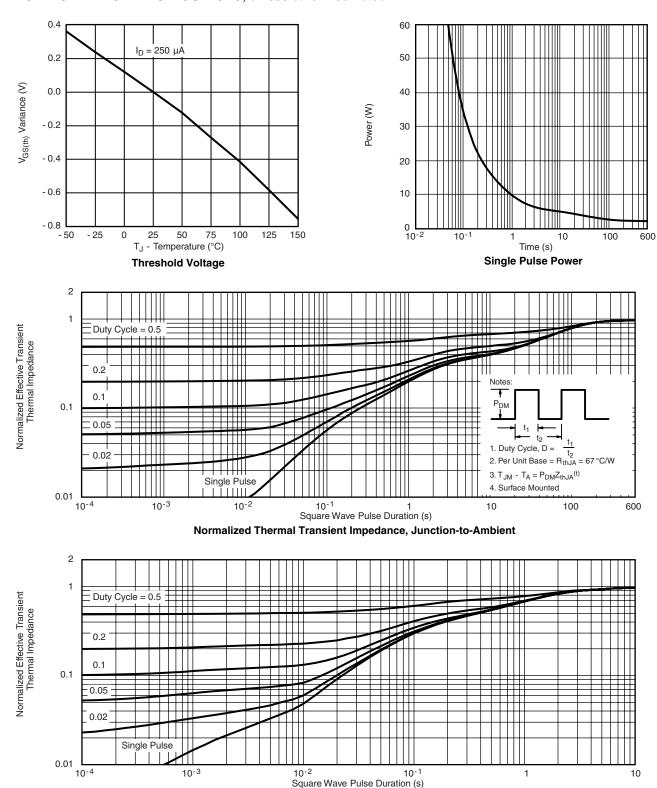
V_{GS} - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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Normalized Thermal Transient Impedance, Junction-to-Foot



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- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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